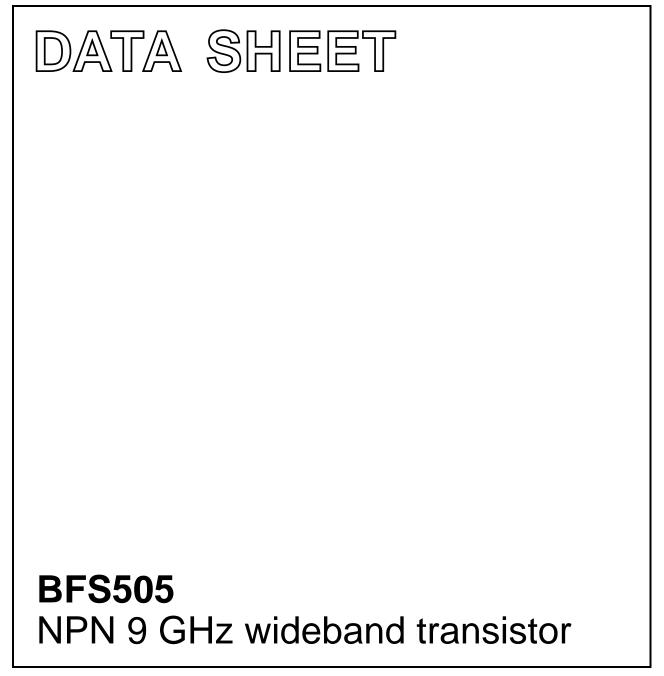
DISCRETE SEMICONDUCTORS



Product specification

September 1995



PINNING

PIN

1

2

3

DESCRIPTION

Code: N0

base

emitter

collector

#### FEATURES

- Low current consumption
- High power gain
- Low noise figure
- High transition frequency
- Gold metallization ensures
  excellent reliability
- SOT323 envelope.

#### DESCRIPTION

NPN transistor in a plastic SOT323 envelope.

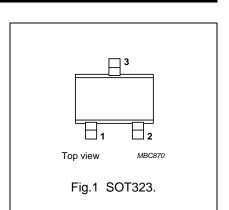
It is intended for low power amplifiers, oscillators and mixers particularly in RF portable communication equipment (cellular phones, cordless phones, pagers) up to 2 GHz.

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-	20	V
V <sub>CES</sub>	collector-emitter voltage	$R_{BE} = 0$	-	-	15	V
I <sub>C</sub>	DC collector current		-	-	18	mA
P <sub>tot</sub>	total power dissipation	up to $T_s = 147 \text{ °C}$ ; note 1	_	_	150	mW
h <sub>FE</sub>	DC current gain	$I_{C} = 5 \text{ mA}; V_{CE} = 6 \text{ V}; T_{j} = 25 \text{ °C}$	60	120	250	
f <sub>T</sub>	transition frequency	$I_C = 5 \text{ mA}; V_{CE} = 6 \text{ V}; \text{ f} = 1 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$	-	9	-	GHz
G <sub>UM</sub>	maximum unilateral power gain	$I_c = 5 \text{ mA}; V_{CE} = 6 \text{ V}; f = 900 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$	-	17	-	dB
F	noise figure	I <sub>c</sub> = 1.25 mA; V <sub>CE</sub> = 6 V; f = 900 MHz; T <sub>amb</sub> = 25 °C	_	1.2	1.7	dB

#### Note

1.  $T_s$  is the temperature at the soldering point of the collector tab.



#### **Product specification**

## **BFS505**

#### LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	-	20	V
V <sub>CES</sub>	collector-emitter voltage	$R_{BE} = 0$	-	15	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	2.5	V
I <sub>C</sub>	DC collector current		-	18	mA
P <sub>tot</sub>	total power dissipation	up to $T_s = 147 \text{ °C}$ ; note 1	-	150	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	175	°C

#### THERMAL RESISTANCE

SYMBOL	PARAMETER	CONDITIONS	THERMAL RESISTANCE		
R <sub>th j-s</sub>	thermal resistance from junction to soldering point	up to T <sub>s</sub> = 147 °C; note 1	190 K/W		

Note

1.  $T_s$  is the temperature at the soldering point of the collector tab.

## **BFS505**

#### CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$ , unless otherwise specified.

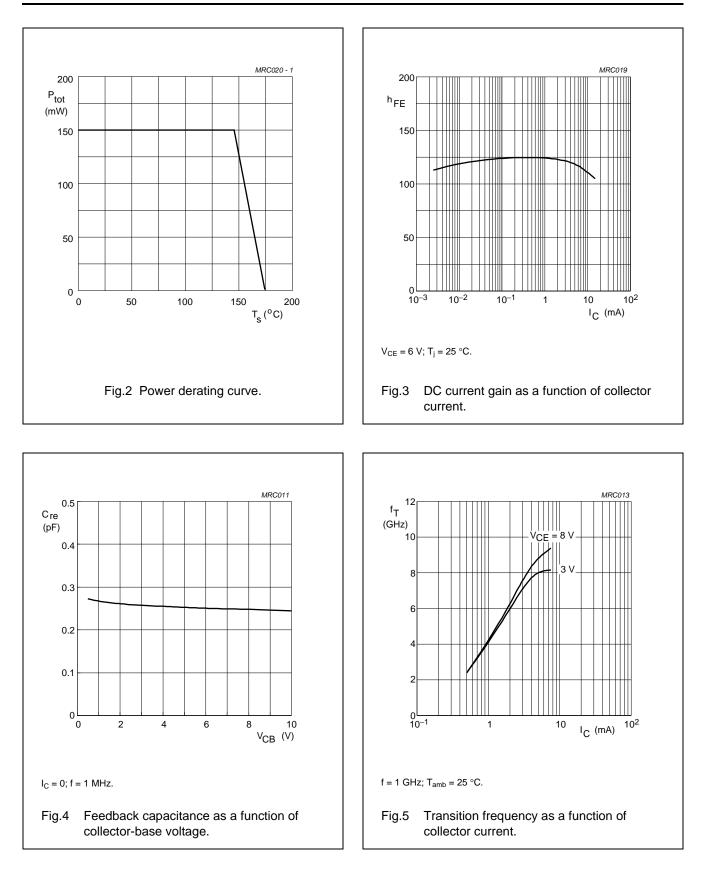
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = 6 V	-	-	50	nA
h <sub>FE</sub>	DC current gain	$I_{C} = 5 \text{ mA}; V_{CE} = 6 \text{ V}$	60	120	250	
C <sub>e</sub>	emitter capacitance	$I_{C} = i_{c} = 0; V_{EB} = 0.5 V; f = 1 MHz$	-	0.4	-	pF
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0; V_{CB} = 6 V; f = 1 MHz$	-	0.4	-	pF
C <sub>re</sub>	feedback capacitance	$I_{C} = 0; V_{CB} = 0.5 V; f = 1 MHz$	-	0.3	-	pF
f <sub>T</sub>	transition frequency	$I_C = 5 \text{ mA}; V_{CE} = 6 \text{ V}; f = 1 \text{ GHz};$ $T_{amb} = 25 ^{\circ}\text{C}$	-	9	-	GHz
G <sub>UM</sub>	maximum unilateral power gain (note 1)	$I_C = 5 \text{ mA}; V_{CE} = 6 \text{ V}; f = 900 \text{ MHz};$ $T_{amb} = 25 ^{\circ}\text{C}$	-	17	-	dB
		$I_C = 5 \text{ mA}; V_{CE} = 6 \text{ V}; f = 2 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$	-	10	-	dB
S <sub>21</sub>   <sup>2</sup>	insertion power gain	$I_C = 5 \text{ mA}; V_{CE} = 6 \text{ V}; f = 900 \text{ MHz};$ $T_{amb} = 25 ^{\circ}\text{C}$	13	14	-	dB
F	noise figure	$\Gamma_{s} = \Gamma_{opt}$ ; I <sub>C</sub> = 1.25 mA; V <sub>CE</sub> = 6 V; f = 900 MHz; T <sub>amb</sub> = 25 °C	-	1.2	1.7	dB
		$\Gamma_{s} = \Gamma_{opt}$ ; I <sub>C</sub> = 5 mA; V <sub>CE</sub> = 6 V; f = 900 MHz; T <sub>amb</sub> = 25 °C	-	1.6	2.1	dB
		$\Gamma_{s} = \Gamma_{opt}$ ; I <sub>C</sub> = 1.25 mA; V <sub>CE</sub> = 6 V; f = 2 GHz; T <sub>amb</sub> = 25 °C	-	1.9	-	dB
P <sub>L1</sub>	output power at 1 dB gain compression	$I_c$ = 5 mA; V <sub>CE</sub> = 6 V; R <sub>L</sub> = 50 Ω; f = 900 MHz; T <sub>amb</sub> = 25 °C	-	4	-	dBm
ITO	third order intercept point	note 2	_	10	-	dBm

#### Notes

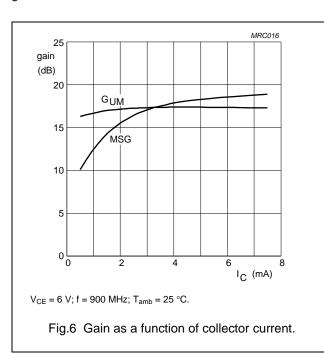
1.  $G_{UM}$  is the maximum unilateral power gain, assuming  $S_{12}$  is zero and

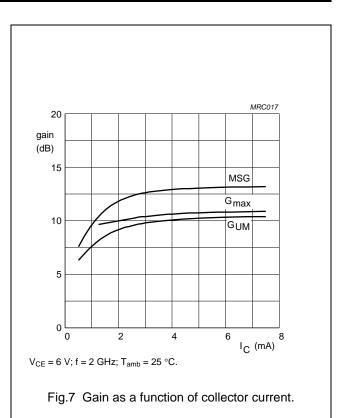
$$G_{UM} = 10 \log \frac{|S_{21}|^2}{(1 - |S_{11}|^2)(1 - |S_{22}|^2)} dB.$$

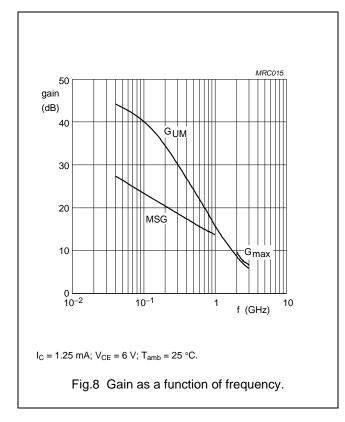
2.  $I_C = 5 \text{ mA}; V_{CE} = 6 \text{ V}; R_L = 50 \Omega; f = 900 \text{ MHz}; T_{amb} = 25 \text{ °C};$  $f_p = 900 \text{ MHz}; f_q = 902 \text{ MHz}; \text{ measured at } f_{(2p-q)} = 898 \text{ MHz and at } f_{(2q-p)} = 904 \text{ MHz}.$ 

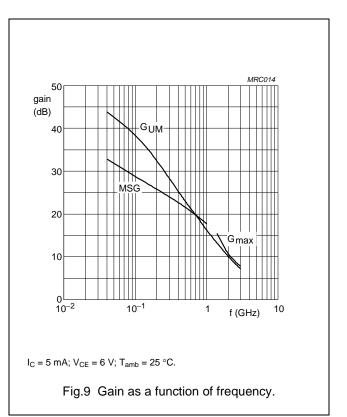


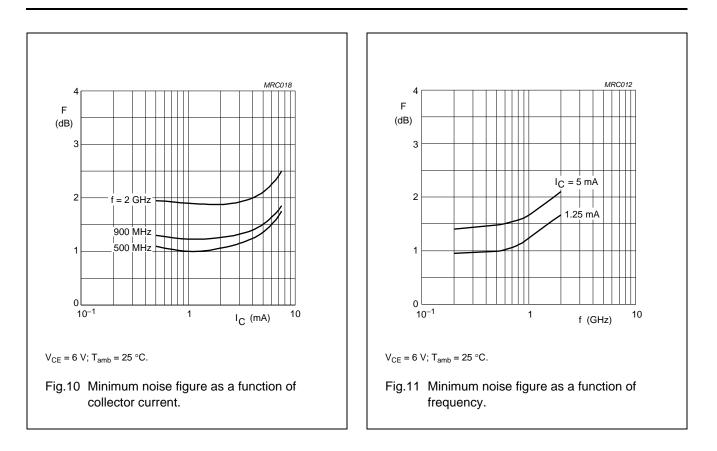
In Figs 6 to 9,  $G_{UM}$  = maximum unilateral power gain; MSG = maximum stable gain;  $G_{max}$  = maximum available gain.



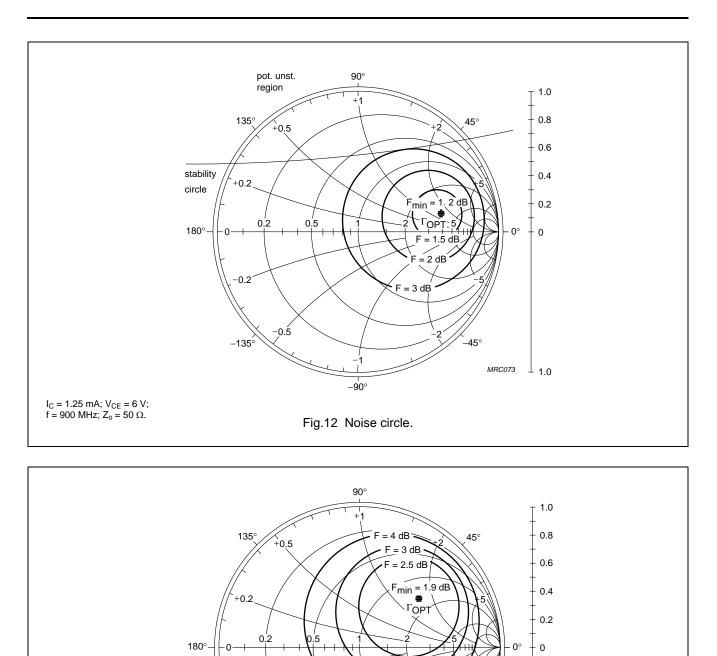








## **BFS505**



 $\label{eq:lc} \begin{array}{l} \mathsf{I}_{\mathsf{C}} = 1.25 \text{ mA}; \, \mathsf{V}_{\mathsf{CE}} = 6 \text{ V}; \\ \mathsf{f} = 2 \text{ GHz}; \, \mathsf{Z}_{\mathsf{o}} = 50 \; \Omega. \end{array}$ 

Fig.13 Noise circle.

-90°

-45

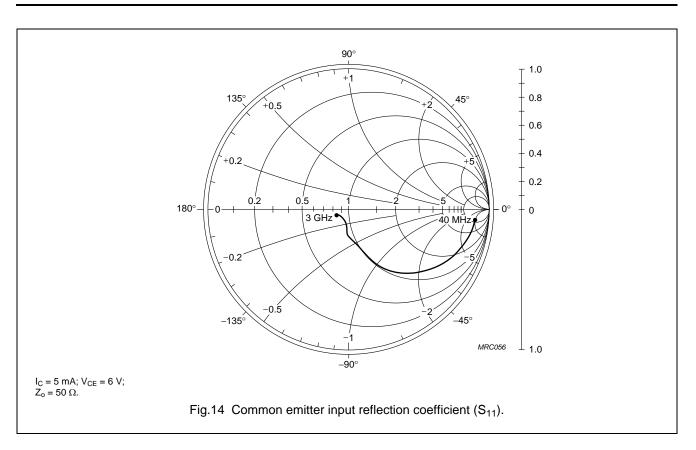
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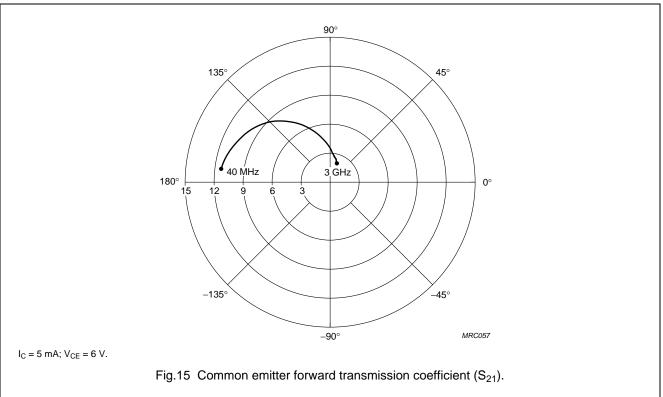
⊥ 1.0

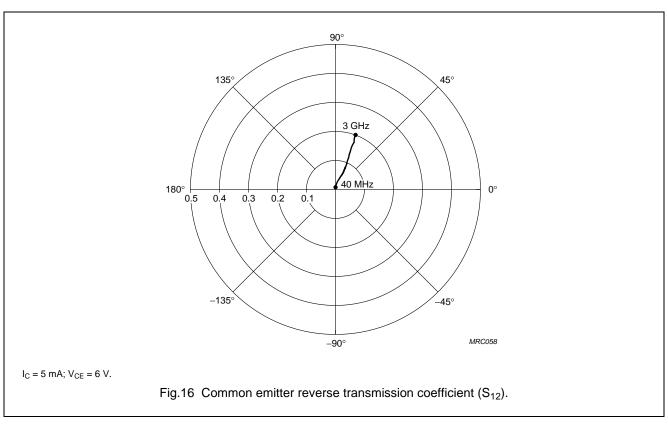
-0.2

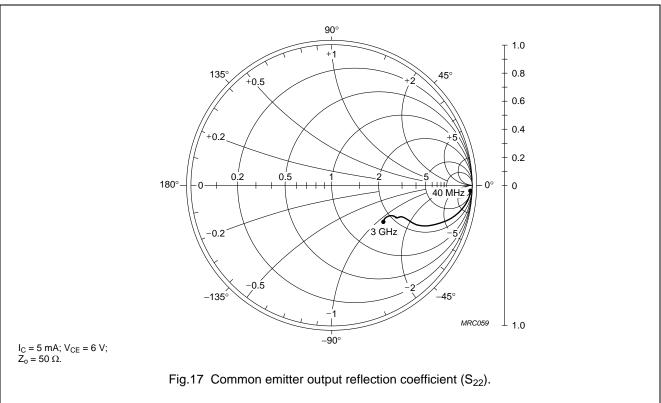
-135°

-0.5

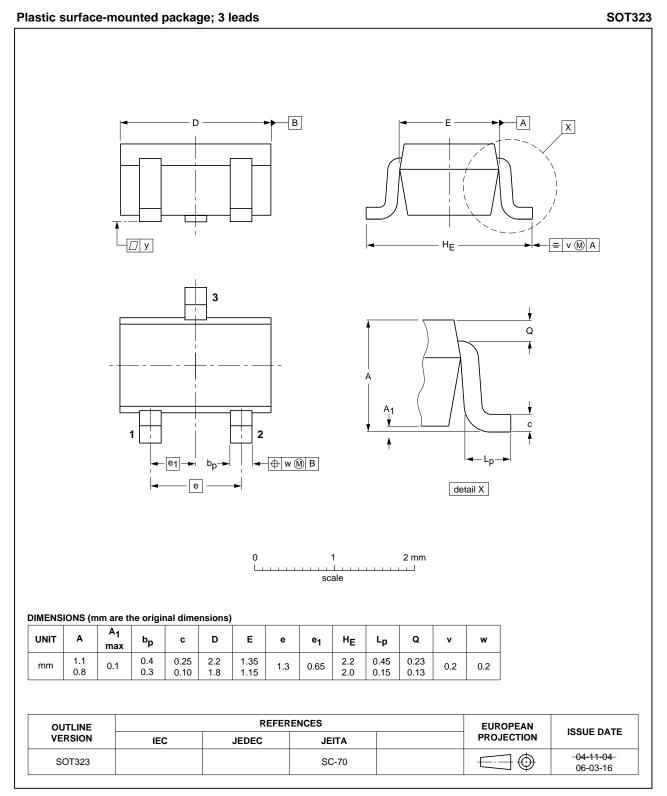








#### PACKAGE OUTLINE



**BFS505** 

#### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Printed in The Netherlands

R77/03/pp14

Date of release: September 1995